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### Understanding **Embedded - FPGAs (Field Programmable Gate Array)**


Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

#### Details

Product Status	Active
Number of LABs/CLBs	9360
Number of Logic Elements/Cells	149760
Total RAM Bits	6635520
Number of I/O	475
Number of Gates	-
Voltage - Supply	1.16V ~ 1.24V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	896-BGA
Supplier Device Package	896-FBGA (31x31)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/intel/ep4cgx150df31c7">https://www.e-xfl.com/product-detail/intel/ep4cgx150df31c7</a>

 Cyclone IV E industrial devices I7 are offered with extended operating temperature range.

## Absolute Maximum Ratings

Absolute maximum ratings define the maximum operating conditions for Cyclone IV devices. The values are based on experiments conducted with the device and theoretical modeling of breakdown and damage mechanisms. The functional operation of the device is not implied at these conditions. Table 1–1 lists the absolute maximum ratings for Cyclone IV devices.



Conditions beyond those listed in Table 1–1 cause permanent damage to the device. Additionally, device operation at the absolute maximum ratings for extended periods of time have adverse effects on the device.

**Table 1–1. Absolute Maximum Ratings for Cyclone IV Devices <sup>(1)</sup>**

Symbol	Parameter	Min	Max	Unit
$V_{CCINT}$	Core voltage, PCI Express® (PCIe®) hard IP block, and transceiver physical coding sublayer (PCS) power supply	–0.5	1.8	V
$V_{CCA}$	Phase-locked loop (PLL) analog power supply	–0.5	3.75	V
$V_{CCD\_PLL}$	PLL digital power supply	–0.5	1.8	V
$V_{CCIO}$	I/O banks power supply	–0.5	3.75	V
$V_{CC\_CLKIN}$	Differential clock input pins power supply	–0.5	4.5	V
$V_{CCH\_GXB}$	Transceiver output buffer power supply	–0.5	3.75	V
$V_{CCA\_GXB}$	Transceiver physical medium attachment (PMA) and auxiliary power supply	–0.5	3.75	V
$V_{CCL\_GXB}$	Transceiver PMA and auxiliary power supply	–0.5	1.8	V
$V_I$	DC input voltage	–0.5	4.2	V
$I_{OUT}$	DC output current, per pin	–25	40	mA
$T_{STG}$	Storage temperature	–65	150	°C
$T_J$	Operating junction temperature	–40	125	°C

**Note to Table 1–1:**

(1) Supply voltage specifications apply to voltage readings taken at the device pins with respect to ground, not at the power supply.

## Maximum Allowed Overshoot or Undershoot Voltage

During transitions, input signals may overshoot to the voltage shown in Table 1–2 and undershoot to –2.0 V for a magnitude of currents less than 100 mA and for periods shorter than 20 ns. Table 1–2 lists the maximum allowed input overshoot voltage and the duration of the overshoot voltage as a percentage over the lifetime of the device. The maximum allowed overshoot duration is specified as a percentage of high-time over the lifetime of the device.

**Table 1-7. Bus Hold Parameter for Cyclone IV Devices (Part 2 of 2) <sup>(1)</sup>**

Parameter	Condition	$V_{CCIO}$ (V)												Unit
		1.2		1.5		1.8		2.5		3.0		3.3		
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
Bus hold trip point	—	0.3	0.9	0.375	1.125	0.68	1.07	0.7	1.7	0.8	2	0.8	2	V

**Note to Table 1-7:**

(1) Bus hold trip points are based on the calculated input voltages from the JEDEC standard.

## OCT Specifications

Table 1-8 lists the variation of OCT without calibration across process, temperature, and voltage (PVT).

**Table 1-8. Series OCT Without Calibration Specifications for Cyclone IV Devices**

Description	$V_{CCIO}$ (V)	Resistance Tolerance		Unit
		Commercial Maximum	Industrial, Extended industrial, and Automotive Maximum	
Series OCT without calibration	3.0	±30	±40	%
	2.5	±30	±40	%
	1.8	±40	±50	%
	1.5	±50	±50	%
	1.2	±50	±50	%

OCT calibration is automatically performed at device power-up for OCT-enabled I/Os.

Table 1-9 lists the OCT calibration accuracy at device power-up.

**Table 1-9. Series OCT with Calibration at Device Power-Up Specifications for Cyclone IV Devices**

Description	$V_{CCIO}$ (V)	Calibration Accuracy		Unit
		Commercial Maximum	Industrial, Extended industrial, and Automotive Maximum	
Series OCT with calibration at device power-up	3.0	±10	±10	%
	2.5	±10	±10	%
	1.8	±10	±10	%
	1.5	±10	±10	%
	1.2	±10	±10	%

The OCT resistance may vary with the variation of temperature and voltage after calibration at device power-up. Use Table 1-10 and Equation 1-1 to determine the final OCT resistance considering the variations after calibration at device power-up. Table 1-10 lists the change percentage of the OCT resistance with voltage and temperature.

**Table 1-10. OCT Variation After Calibration at Device Power-Up for Cyclone IV Devices**

Nominal Voltage	dR/dT (%/°C)	dR/dV (%/mV)
3.0	0.262	-0.026
2.5	0.234	-0.039
1.8	0.219	-0.086
1.5	0.199	-0.136
1.2	0.161	-0.288

**Equation 1-1. Final OCT Resistance (1), (2), (3), (4), (5), (6)**

$$\Delta R_V = (V_2 - V_1) \times 1000 \times dR/dV \text{ — (7)}$$

$$\Delta R_T = (T_2 - T_1) \times dR/dT \text{ — (8)}$$

$$\text{For } \Delta R_x < 0; MF_x = 1 / (|\Delta R_x|/100 + 1) \text{ — (9)}$$

$$\text{For } \Delta R_x > 0; MF_x = \Delta R_x / 100 + 1 \text{ — (10)}$$

$$MF = MF_V \times MF_T \text{ — (11)}$$

$$R_{\text{final}} = R_{\text{initial}} \times MF \text{ — (12)}$$

**Notes to Equation 1-1:**

- (1)  $T_2$  is the final temperature.
- (2)  $T_1$  is the initial temperature.
- (3) MF is multiplication factor.
- (4)  $R_{\text{final}}$  is final resistance.
- (5)  $R_{\text{initial}}$  is initial resistance.
- (6) Subscript  $x$  refers to both  $v$  and  $t$ .
- (7)  $\Delta R_V$  is a variation of resistance with voltage.
- (8)  $\Delta R_T$  is a variation of resistance with temperature.
- (9)  $dR/dT$  is the change percentage of resistance with temperature after calibration at device power-up.
- (10)  $dR/dV$  is the change percentage of resistance with voltage after calibration at device power-up.
- (11)  $V_2$  is final voltage.
- (12)  $V_1$  is the initial voltage.

## Internal Weak Pull-Up and Weak Pull-Down Resistor

Table 1-12 lists the weak pull-up and pull-down resistor values for Cyclone IV devices.

**Table 1-12. Internal Weak Pull-Up and Weak Pull-Down Resistor Values for Cyclone IV Devices <sup>(1)</sup>**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
R <sub>PU</sub>	Value of the I/O pin pull-up resistor before and during configuration, as well as user mode if you enable the programmable pull-up resistor option	V <sub>CCIO</sub> = 3.3 V ± 5% <sup>(2), (3)</sup>	7	25	41	kΩ
		V <sub>CCIO</sub> = 3.0 V ± 5% <sup>(2), (3)</sup>	7	28	47	kΩ
		V <sub>CCIO</sub> = 2.5 V ± 5% <sup>(2), (3)</sup>	8	35	61	kΩ
		V <sub>CCIO</sub> = 1.8 V ± 5% <sup>(2), (3)</sup>	10	57	108	kΩ
		V <sub>CCIO</sub> = 1.5 V ± 5% <sup>(2), (3)</sup>	13	82	163	kΩ
		V <sub>CCIO</sub> = 1.2 V ± 5% <sup>(2), (3)</sup>	19	143	351	kΩ
R <sub>PD</sub>	Value of the I/O pin pull-down resistor before and during configuration	V <sub>CCIO</sub> = 3.3 V ± 5% <sup>(4)</sup>	6	19	30	kΩ
		V <sub>CCIO</sub> = 3.0 V ± 5% <sup>(4)</sup>	6	22	36	kΩ
		V <sub>CCIO</sub> = 2.5 V ± 5% <sup>(4)</sup>	6	25	43	kΩ
		V <sub>CCIO</sub> = 1.8 V ± 5% <sup>(4)</sup>	7	35	71	kΩ
		V <sub>CCIO</sub> = 1.5 V ± 5% <sup>(4)</sup>	8	50	112	kΩ

**Notes to Table 1-12:**

- All I/O pins have an option to enable weak pull-up except the configuration, test, and JTAG pins. The weak pull-down feature is only available for JTAG TCK.
- Pin pull-up resistance values may be lower if an external source drives the pin higher than V<sub>CCIO</sub>.
- R<sub>PU</sub> = (V<sub>CCIO</sub> - V<sub>I</sub>)/I<sub>R\_PU</sub>  
 Minimum condition: -40°C; V<sub>CCIO</sub> = V<sub>CC</sub> + 5%, V<sub>I</sub> = V<sub>CC</sub> + 5% - 50 mV;  
 Typical condition: 25°C; V<sub>CCIO</sub> = V<sub>CC</sub>, V<sub>I</sub> = 0 V;  
 Maximum condition: 100°C; V<sub>CCIO</sub> = V<sub>CC</sub> - 5%, V<sub>I</sub> = 0 V; in which V<sub>I</sub> refers to the input voltage at the I/O pin.
- R<sub>PD</sub> = V<sub>I</sub>/I<sub>R\_PD</sub>  
 Minimum condition: -40°C; V<sub>CCIO</sub> = V<sub>CC</sub> + 5%, V<sub>I</sub> = 50 mV;  
 Typical condition: 25°C; V<sub>CCIO</sub> = V<sub>CC</sub>, V<sub>I</sub> = V<sub>CC</sub> - 5%;  
 Maximum condition: 100°C; V<sub>CCIO</sub> = V<sub>CC</sub> - 5%, V<sub>I</sub> = V<sub>CC</sub> - 5%; in which V<sub>I</sub> refers to the input voltage at the I/O pin.

## Hot-Socketing


Table 1-13 lists the hot-socketing specifications for Cyclone IV devices.

**Table 1-13. Hot-Socketing Specifications for Cyclone IV Devices**

Symbol	Parameter	Maximum
I <sub>IOPIN(DC)</sub>	DC current per I/O pin	300 μA
I <sub>IOPIN(AC)</sub>	AC current per I/O pin	8 mA <sup>(1)</sup>
I <sub>XCVRTX(DC)</sub>	DC current per transceiver TX pin	100 mA
I <sub>XCVRRX(DC)</sub>	DC current per transceiver RX pin	50 mA

**Note to Table 1-13:**

- The I/O ramp rate is 10 ns or more. For ramp rates faster than 10 ns, |I<sub>IOPIN</sub>| = C dv/dt, in which C is the I/O pin capacitance and dv/dt is the slew rate.

 During hot-socketing, the I/O pin capacitance is less than 15 pF and the clock pin capacitance is less than 20 pF.

## Schmitt Trigger Input

Cyclone IV devices support Schmitt trigger input on the TDI, TMS, TCK, nSTATUS, nCONFIG, nCE, CONF\_DONE, and DCLK pins. A Schmitt trigger feature introduces hysteresis to the input signal for improved noise immunity, especially for signals with slow edge rate. Table 1–14 lists the hysteresis specifications across the supported  $V_{CCIO}$  range for Schmitt trigger inputs in Cyclone IV devices.

**Table 1–14. Hysteresis Specifications for Schmitt Trigger Input in Cyclone IV Devices**

Symbol	Parameter	Conditions (V)	Minimum	Unit
$V_{SCHMITT}$	Hysteresis for Schmitt trigger input	$V_{CCIO} = 3.3$	200	mV
		$V_{CCIO} = 2.5$	200	mV
		$V_{CCIO} = 1.8$	140	mV
		$V_{CCIO} = 1.5$	110	mV

## I/O Standard Specifications

The following tables list input voltage sensitivities ( $V_{IH}$  and  $V_{IL}$ ), output voltage ( $V_{OH}$  and  $V_{OL}$ ), and current drive characteristics ( $I_{OH}$  and  $I_{OL}$ ), for various I/O standards supported by Cyclone IV devices. Table 1–15 through Table 1–20 provide the I/O standard specifications for Cyclone IV devices.

**Table 1–15. Single-Ended I/O Standard Specifications for Cyclone IV Devices <sup>(1), (2)</sup>**

I/O Standard	$V_{CCIO}$ (V)			$V_{IL}$ (V)		$V_{IH}$ (V)		$V_{OL}$ (V)	$V_{OH}$ (V)	$I_{OL}$ (mA) <sup>(4)</sup>	$I_{OH}$ (mA) <sup>(4)</sup>
	Min	Typ	Max	Min	Max	Min	Max	Max	Min		
3.3-V LVTTTL <sup>(3)</sup>	3.135	3.3	3.465	—	0.8	1.7	3.6	0.45	2.4	4	–4
3.3-V LVCMOS <sup>(3)</sup>	3.135	3.3	3.465	—	0.8	1.7	3.6	0.2	$V_{CCIO} - 0.2$	2	–2
3.0-V LVTTTL <sup>(3)</sup>	2.85	3.0	3.15	–0.3	0.8	1.7	$V_{CCIO} + 0.3$	0.45	2.4	4	–4
3.0-V LVCMOS <sup>(3)</sup>	2.85	3.0	3.15	–0.3	0.8	1.7	$V_{CCIO} + 0.3$	0.2	$V_{CCIO} - 0.2$	0.1	–0.1
2.5 V <sup>(3)</sup>	2.375	2.5	2.625	–0.3	0.7	1.7	$V_{CCIO} + 0.3$	0.4	2.0	1	–1
1.8 V	1.71	1.8	1.89	–0.3	$0.35 \times V_{CCIO}$	$0.65 \times V_{CCIO}$	2.25	0.45	$V_{CCIO} - 0.45$	2	–2
1.5 V	1.425	1.5	1.575	–0.3	$0.35 \times V_{CCIO}$	$0.65 \times V_{CCIO}$	$V_{CCIO} + 0.3$	$0.25 \times V_{CCIO}$	$0.75 \times V_{CCIO}$	2	–2
1.2 V	1.14	1.2	1.26	–0.3	$0.35 \times V_{CCIO}$	$0.65 \times V_{CCIO}$	$V_{CCIO} + 0.3$	$0.25 \times V_{CCIO}$	$0.75 \times V_{CCIO}$	2	–2
3.0-V PCI	2.85	3.0	3.15	—	$0.3 \times V_{CCIO}$	$0.5 \times V_{CCIO}$	$V_{CCIO} + 0.3$	$0.1 \times V_{CCIO}$	$0.9 \times V_{CCIO}$	1.5	–0.5
3.0-V PCI-X	2.85	3.0	3.15	—	$0.35 \times V_{CCIO}$	$0.5 \times V_{CCIO}$	$V_{CCIO} + 0.3$	$0.1 \times V_{CCIO}$	$0.9 \times V_{CCIO}$	1.5	–0.5

### Notes to Table 1–15:

- (1) For voltage-referenced receiver input waveform and explanation of terms used in Table 1–15, refer to “Glossary” on page 1–37.
- (2) AC load  $CL = 10$  pF
- (3) For more information about interfacing Cyclone IV devices with 3.3/3.0/2.5-V LVTTTL/LVCMOS I/O standards, refer to *AN 447: Interfacing Cyclone III and Cyclone IV Devices with 3.3/3.0/2.5-V LVTTTL/LVCMOS I/O Systems*.
- (4) To meet the  $I_{OL}$  and  $I_{OH}$  specifications, you must set the current strength settings accordingly. For example, to meet the 3.3-V LVTTTL specification (4 mA), set the current strength settings to 4 mA or higher. Setting at lower current strength may not meet the  $I_{OL}$  and  $I_{OH}$  specifications in the handbook.

For more information about receiver input and transmitter output waveforms, and for other differential I/O standards, refer to the *I/O Features in Cyclone IV Devices* chapter.

**Table 1–18. Differential SSTL I/O Standard Specifications for Cyclone IV Devices <sup>(1)</sup>**

I/O Standard	V <sub>CCIO</sub> (V)			V <sub>Swing(DC)</sub> (V)		V <sub>X(AC)</sub> (V)			V <sub>Swing(AC)</sub> (V)		V <sub>Ox(AC)</sub> (V)		
	Min	Typ	Max	Min	Max	Min	Typ	Max	Min	Max	Min	Typ	Max
SSTL-2 Class I, II	2.375	2.5	2.625	0.36	V <sub>CCIO</sub>	V <sub>CCIO</sub> /2 – 0.2	—	V <sub>CCIO</sub> /2 + 0.2	0.7	V <sub>CCIO</sub>	V <sub>CCIO</sub> /2 – 0.125	—	V <sub>CCIO</sub> /2 + 0.125
SSTL-18 Class I, II	1.7	1.8	1.90	0.25	V <sub>CCIO</sub>	V <sub>CCIO</sub> /2 – 0.175	—	V <sub>CCIO</sub> /2 + 0.175	0.5	V <sub>CCIO</sub>	V <sub>CCIO</sub> /2 – 0.125	—	V <sub>CCIO</sub> /2 + 0.125

Note to Table 1–18:

(1) Differential SSTL requires a V<sub>REF</sub> input.

**Table 1–19. Differential HSTL I/O Standard Specifications for Cyclone IV Devices <sup>(1)</sup>**

I/O Standard	V <sub>CCIO</sub> (V)			V <sub>DIF(DC)</sub> (V)		V <sub>X(AC)</sub> (V)			V <sub>CM(DC)</sub> (V)			V <sub>DIF(AC)</sub> (V)	
	Min	Typ	Max	Min	Max	Min	Typ	Max	Min	Typ	Max	Min	Max
HSTL-18 Class I, II	1.71	1.8	1.89	0.2	—	0.85	—	0.95	0.85	—	0.95	0.4	—
HSTL-15 Class I, II	1.425	1.5	1.575	0.2	—	0.71	—	0.79	0.71	—	0.79	0.4	—
HSTL-12 Class I, II	1.14	1.2	1.26	0.16	V <sub>CCIO</sub>	0.48 x V <sub>CCIO</sub>	—	0.52 x V <sub>CCIO</sub>	0.48 x V <sub>CCIO</sub>	—	0.52 x V <sub>CCIO</sub>	0.3	0.48 x V <sub>CCIO</sub>

Note to Table 1–19:

(1) Differential HSTL requires a V<sub>REF</sub> input.

**Table 1–20. Differential I/O Standard Specifications for Cyclone IV Devices <sup>(1)</sup> (Part 1 of 2)**

I/O Standard	V <sub>CCIO</sub> (V)			V <sub>ID</sub> (mV)		V <sub>ICM</sub> (V) <sup>(2)</sup>			V <sub>OD</sub> (mV) <sup>(3)</sup>			V <sub>OS</sub> (V) <sup>(3)</sup>		
	Min	Typ	Max	Min	Max	Min	Condition	Max	Min	Typ	Max	Min	Typ	Max
LVPECL (Row I/Os) <sup>(6)</sup>	2.375	2.5	2.625	100	—	0.05	D <sub>MAX</sub> ≤ 500 Mbps	1.80	—	—	—	—	—	—
						0.55	500 Mbps ≤ D <sub>MAX</sub> ≤ 700 Mbps	1.80						
						1.05	D <sub>MAX</sub> > 700 Mbps	1.55						
LVPECL (Column I/Os) <sup>(6)</sup>	2.375	2.5	2.625	100	—	0.05	D <sub>MAX</sub> ≤ 500 Mbps	1.80	—	—	—	—	—	—
						0.55	500 Mbps ≤ D <sub>MAX</sub> ≤ 700 Mbps	1.80						
						1.05	D <sub>MAX</sub> > 700 Mbps	1.55						
LVDS (Row I/Os)	2.375	2.5	2.625	100	—	0.05	D <sub>MAX</sub> ≤ 500 Mbps	1.80	247	—	600	1.125	1.25	1.375
						0.55	500 Mbps ≤ D <sub>MAX</sub> ≤ 700 Mbps	1.80						
						1.05	D <sub>MAX</sub> > 700 Mbps	1.55						

**Table 1-20. Differential I/O Standard Specifications for Cyclone IV Devices <sup>(1)</sup> (Part 2 of 2)**

I/O Standard	V <sub>CCIO</sub> (V)			V <sub>ID</sub> (mV)		V <sub>ICM</sub> (V) <sup>(2)</sup>			V <sub>OD</sub> (mV) <sup>(3)</sup>			V <sub>OS</sub> (V) <sup>(3)</sup>			
	Min	Typ	Max	Min	Max	Min	Condition	Max	Min	Typ	Max	Min	Typ	Max	
LVDS (Column I/Os)	2.375	2.5	2.625	100	—	0.05	$D_{MAX} \leq 500 \text{ Mbps}$	1.80	247	—	600	1.125	1.25	1.375	
						0.55	$500 \text{ Mbps} \leq D_{MAX} \leq 700 \text{ Mbps}$	1.80							
						1.05	$D_{MAX} > 700 \text{ Mbps}$	1.55							
BLVDS (Row I/Os) <sup>(4)</sup>	2.375	2.5	2.625	100	—	—	—	—	—	—	—	—	—	—	—
BLVDS (Column I/Os) <sup>(4)</sup>	2.375	2.5	2.625	100	—	—	—	—	—	—	—	—	—	—	—
mini-LVDS (Row I/Os) <sup>(5)</sup>	2.375	2.5	2.625	—	—	—	—	—	300	—	600	1.0	1.2	1.4	
mini-LVDS (Column I/Os) <sup>(5)</sup>	2.375	2.5	2.625	—	—	—	—	—	300	—	600	1.0	1.2	1.4	
RSDS <sup>®</sup> (Row I/Os) <sup>(5)</sup>	2.375	2.5	2.625	—	—	—	—	—	100	200	600	0.5	1.2	1.5	
RSDS (Column I/Os) <sup>(5)</sup>	2.375	2.5	2.625	—	—	—	—	—	100	200	600	0.5	1.2	1.5	
PPDS (Row I/Os) <sup>(5)</sup>	2.375	2.5	2.625	—	—	—	—	—	100	200	600	0.5	1.2	1.4	
PPDS (Column I/Os) <sup>(5)</sup>	2.375	2.5	2.625	—	—	—	—	—	100	200	600	0.5	1.2	1.4	

**Notes to Table 1-20:**

- (1) For an explanation of terms used in Table 1-20, refer to “Glossary” on page 1-37.
- (2) V<sub>IN</sub> range:  $0 \text{ V} \leq V_{IN} \leq 1.85 \text{ V}$ .
- (3) R<sub>L</sub> range:  $90 \leq R_L \leq 110 \Omega$ .
- (4) There are no fixed V<sub>IN</sub>, V<sub>OD</sub>, and V<sub>OS</sub> specifications for BLVDS. They depend on the system topology.
- (5) The Mini-LVDS, RSDS, and PPDS standards are only supported at the output pins.
- (6) The LVPECL I/O standard is only supported on dedicated clock input pins. This I/O standard is not supported for output pins.



## Transceiver Performance Specifications

Table 1-21 lists the Cyclone IV GX transceiver specifications.

**Table 1-21. Transceiver Specification for Cyclone IV GX Devices (Part 1 of 4)**

Symbol/ Description	Conditions	C6			C7, 17			C8			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
<b>Reference Clock</b>											
Supported I/O Standards	1.2 V PCML, 1.5 V PCML, 3.3 V PCML, Differential LVPECL, LVDS, HCSL										
Input frequency from REFCLK input pins	—	50	—	156.25	50	—	156.25	50	—	156.25	MHz
Spread-spectrum modulating clock frequency	Physical interface for PCI Express (PIPE) mode	30	—	33	30	—	33	30	—	33	kHz
Spread-spectrum downspread	PIPE mode	—	0 to -0.5%	—	—	0 to -0.5%	—	—	0 to -0.5%	—	—
Peak-to-peak differential input voltage	—	0.1	—	1.6	0.1	—	1.6	0.1	—	1.6	V
V <sub>ICM</sub> (AC coupled)	—	1100 ± 5%			1100 ± 5%			1100 ± 5%			mV
V <sub>ICM</sub> (DC coupled)	HCSL I/O standard for PCIe reference clock	250	—	550	250	—	550	250	—	550	mV
Transmitter REFCLK Phase Noise <sup>(1)</sup>	Frequency offset = 1 MHz – 8 MHz	—	—	-123	—	—	-123	—	—	-123	dBc/Hz
Transmitter REFCLK Total Jitter <sup>(1)</sup>		—	—	42.3	—	—	42.3	—	—	42.3	ps
R <sub>ref</sub>	—	—	2000 ± 1%	—	—	2000 ± 1%	—	—	2000 ± 1%	—	Ω
<b>Transceiver Clock</b>											
cal_blk_clk clock frequency	—	10	—	125	10	—	125	10	—	125	MHz
fixedclk clock frequency	PCIe Receiver Detect	—	125	—	—	125	—	—	125	—	MHz
reconfig_clk clock frequency	Dynamic reconfiguration clock frequency	2.5/ 37.5 <sup>(2)</sup>	—	50	2.5/ 37.5 <sup>(2)</sup>	—	50	2.5/ 37.5 <sup>(2)</sup>	—	50	MHz
Delta time between reconfig_clk	—	—	—	2	—	—	2	—	—	2	ms
Transceiver block minimum power-down pulse width	—	—	1	—	—	1	—	—	1	—	μs

**Table 1-21. Transceiver Specification for Cyclone IV GX Devices (Part 3 of 4)**

Symbol/ Description	Conditions	C6			C7, I7			C8			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Signal detect/loss threshold	PIPE mode	65	—	175	65	—	175	65	—	175	mV
$t_{LTR}$ (10)	—	—	—	75	—	—	75	—	—	75	$\mu$ s
$t_{LTR-LTD\_Manual}$ (11)	—	15	—	—	15	—	—	15	—	—	$\mu$ s
$t_{LTD}$ (12)	—	0	100	4000	0	100	4000	0	100	4000	ns
$t_{LTD\_Manual}$ (13)	—	—	—	4000	—	—	4000	—	—	4000	ns
$t_{LTD\_Auto}$ (14)	—	—	—	4000	—	—	4000	—	—	4000	ns
Receiver buffer and CDR offset cancellation time (per channel)	—	—	—	17000	—	—	17000	—	—	17000	recon fig_c lk cycles
Programmable DC gain	DC Gain Setting = 0	—	0	—	—	0	—	—	0	—	dB
	DC Gain Setting = 1	—	3	—	—	3	—	—	3	—	dB
	DC Gain Setting = 2	—	6	—	—	6	—	—	6	—	dB
<b>Transmitter</b>											
Supported I/O Standards	1.5 V PCML										
Data rate (F324 and smaller package)	—	600	—	2500	600	—	2500	600	—	2500	Mbps
Data rate (F484 and larger package)	—	600	—	3125	600	—	3125	600	—	2500	Mbps
$V_{OCM}$	0.65 V setting	—	650	—	—	650	—	—	650	—	mV
Differential on-chip termination resistors	100- $\Omega$ setting	—	100	—	—	100	—	—	100	—	$\Omega$
	150- $\Omega$ setting	—	150	—	—	150	—	—	150	—	$\Omega$
Differential and common mode return loss	PIPE, CPRI LV, Serial Rapid I/O SR, SDI, XAUI, SATA	Compliant									—
Rise time	—	50	—	200	50	—	200	50	—	200	ps
Fall time	—	50	—	200	50	—	200	50	—	200	ps
Intra-differential pair skew	—	—	—	15	—	—	15	—	—	15	ps
Intra-transceiver block skew	—	—	—	120	—	—	120	—	—	120	ps


**Table 1–21. Transceiver Specification for Cyclone IV GX Devices (Part 4 of 4)**

Symbol/ Description	Conditions	C6			C7, I7			C8			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
<b>PLD-Transceiver Interface</b>											
Interface speed (F324 and smaller package)	—	25	—	125	25	—	125	25	—	125	MHz
Interface speed (F484 and larger package)	—	25	—	156.25	25	—	156.25	25	—	156.25	MHz
Digital reset pulse width	—	Minimum is 2 parallel clock cycles									

**Notes to Table 1–21:**

- (1) This specification is valid for transmitter output jitter specification with a maximum total jitter value of 112 ps, typically for 3.125 Gbps SRIO and XAUI protocols.
- (2) The minimum `reconfig_clk` frequency is 2.5 MHz if the transceiver channel is configured in **Transmitter Only** mode. The minimum `reconfig_clk` frequency is 37.5 MHz if the transceiver channel is configured in **Receiver Only** or **Receiver and Transmitter** mode.
- (3) The device cannot tolerate prolonged operation at this absolute maximum.
- (4) The rate matcher supports only up to  $\pm 300$  parts per million (ppm).
- (5) Supported for the F169 and F324 device packages only.
- (6) Supported for the F484, F672, and F896 device packages only. Pending device characterization.
- (7) To support CDR ppm tolerance greater than  $\pm 300$  ppm, implement ppm detector in user logic and configure CDR to Manual Lock Mode.
- (8) Asynchronous spread-spectrum clocking is not supported.
- (9) For the EP4CGX30 (F484 package only), EP4CGX50, and EP4CGX75 devices, the CDR ppl tolerance is  $\pm 200$  ppm.
- (10) Time taken until `p11_locked` goes high after `p11_powerdown` deasserts.
- (11) Time that the CDR must be kept in lock-to-reference mode after `rx_analogreset` deasserts and before `rx_locktodata` is asserted in manual mode.
- (12) Time taken to recover valid data after the `rx_locktodata` signal is asserted in manual mode (Figure 1–2), or after `rx_freqlocked` signal goes high in automatic mode (Figure 1–3).
- (13) Time taken to recover valid data after the `rx_locktodata` signal is asserted in manual mode.
- (14) Time taken to recover valid data after the `rx_freqlocked` signal goes high in automatic mode.
- (15) To support data rates lower than the minimum specification through oversampling, use the CDR in LTR mode only.

Figure 1-2 shows the lock time parameters in manual mode.

 LTD = lock-to-data. LTR = lock-to-reference.

**Figure 1-2. Lock Time Parameters for Manual Mode**

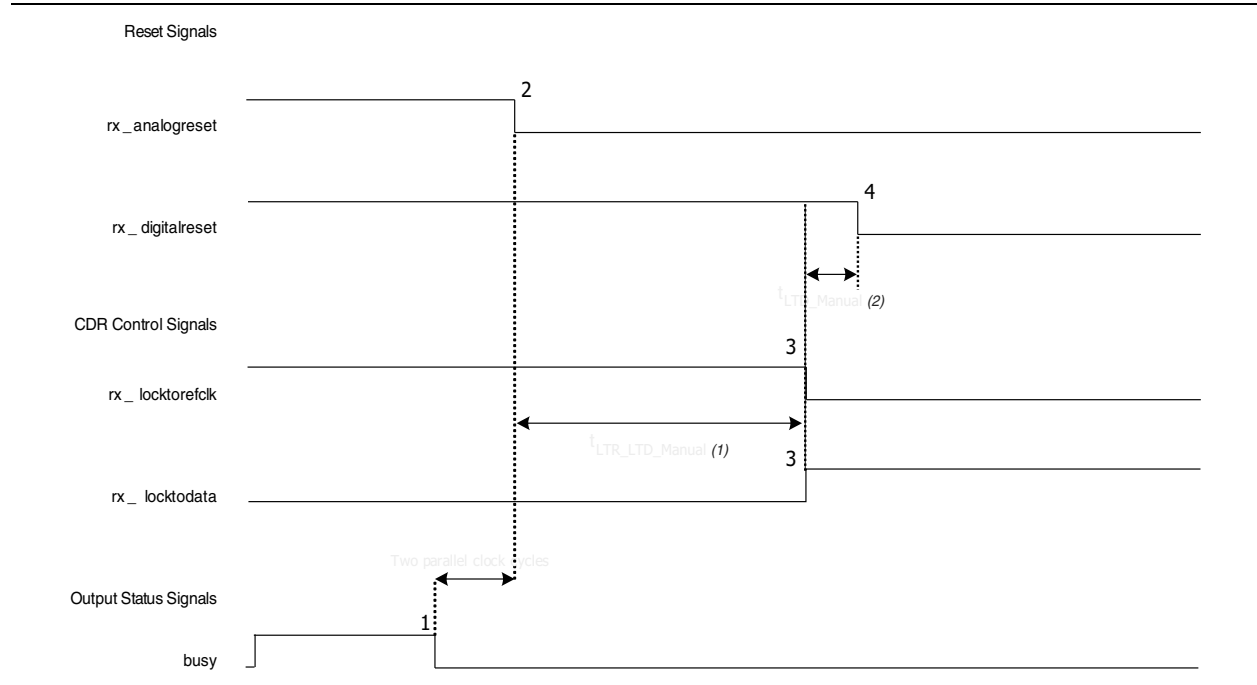


Figure 1-3 shows the lock time parameters in automatic mode.

**Figure 1-3. Lock Time Parameters for Automatic Mode**

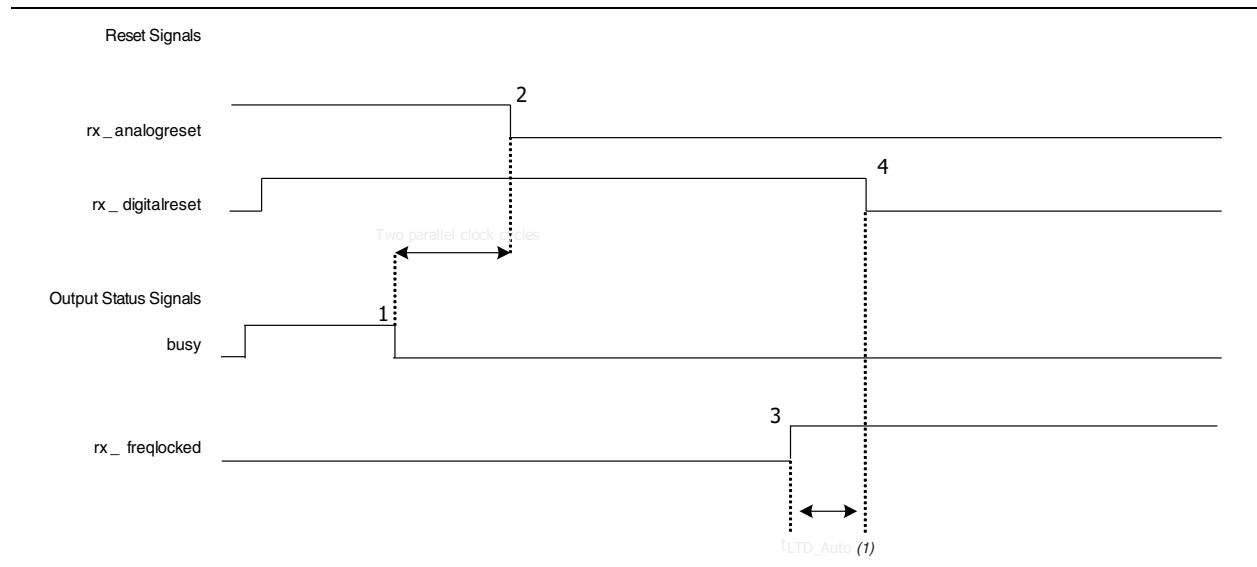


Figure 1-4 shows the differential receiver input waveform.

**Figure 1-4. Receiver Input Waveform**

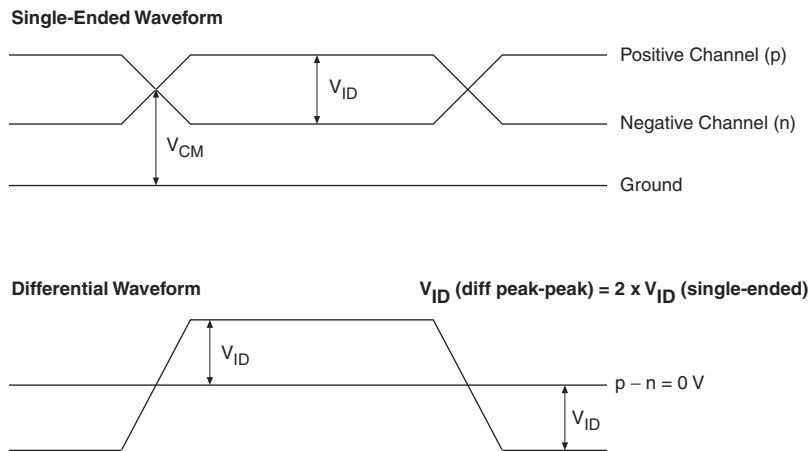


Figure 1-5 shows the transmitter output waveform.

**Figure 1-5. Transmitter Output Waveform**

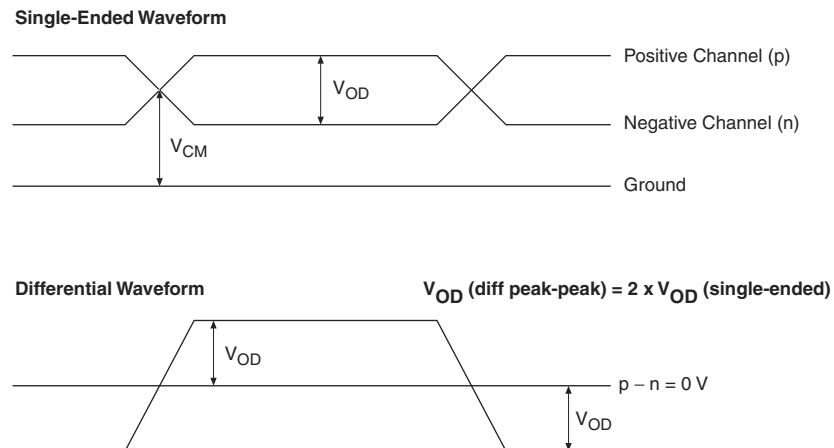


Table 1-22 lists the typical  $V_{OD}$  for Tx term that equals  $100 \Omega$ .

**Table 1-22. Typical  $V_{OD}$  Setting, Tx Term =  $100 \Omega$**

Symbol	$V_{OD}$ Setting (mV)					
	1	2	3	4 (1)	5	6
$V_{OD}$ differential peak to peak typical (mV)	400	600	800	900	1000	1200

**Note to Table 1-22:**

(1) This setting is required for compliance with the PCIe protocol.

Table 1-23 lists the Cyclone IV GX transceiver block AC specifications.

**Table 1-23. Transceiver Block AC Specification for Cyclone IV GX Devices <sup>(1), (2)</sup>**

Symbol/ Description	Conditions	C6			C7, I7			C8			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
<b>PCIe Transmit Jitter Generation <sup>(3)</sup></b>											
Total jitter at 2.5 Gbps (Gen1)	Compliance pattern	—	—	0.25	—	—	0.25	—	—	0.25	UI
<b>PCIe Receiver Jitter Tolerance <sup>(3)</sup></b>											
Total jitter at 2.5 Gbps (Gen1)	Compliance pattern	> 0.6			> 0.6			> 0.6			UI
<b>GIGE Transmit Jitter Generation <sup>(4)</sup></b>											
Deterministic jitter (peak-to-peak)	Pattern = CRPAT	—	—	0.14	—	—	0.14	—	—	0.14	UI
Total jitter (peak-to-peak)	Pattern = CRPAT	—	—	0.279	—	—	0.279	—	—	0.279	UI
<b>GIGE Receiver Jitter Tolerance <sup>(4)</sup></b>											
Deterministic jitter tolerance (peak-to-peak)	Pattern = CJPAT	> 0.4			> 0.4			> 0.4			UI
Combined deterministic and random jitter tolerance (peak-to-peak)	Pattern = CJPAT	> 0.66			> 0.66			> 0.66			UI

**Notes to Table 1-23:**

- (1) Dedicated `refclk` pins were used to drive the input reference clocks.
- (2) The jitter numbers specified are valid for the stated conditions only.
- (3) The jitter numbers for PIPE are compliant to the PCIe Base Specification 2.0.
- (4) The jitter numbers for GIGE are compliant to the IEEE802.3-2002 Specification.

## Core Performance Specifications

The following sections describe the clock tree specifications, PLLs, embedded multiplier, memory block, and configuration specifications for Cyclone IV Devices.

### Clock Tree Specifications

Table 1-24 lists the clock tree specifications for Cyclone IV devices.

**Table 1-24. Clock Tree Performance for Cyclone IV Devices (Part 1 of 2)**

Device	Performance								Unit
	C6	C7	C8	C8L <sup>(1)</sup>	C9L <sup>(1)</sup>	I7	I8L <sup>(1)</sup>	A7	
EP4CE6	500	437.5	402	362	265	437.5	362	402	MHz
EP4CE10	500	437.5	402	362	265	437.5	362	402	MHz
EP4CE15	500	437.5	402	362	265	437.5	362	402	MHz
EP4CE22	500	437.5	402	362	265	437.5	362	402	MHz
EP4CE30	500	437.5	402	362	265	437.5	362	402	MHz
EP4CE40	500	437.5	402	362	265	437.5	362	402	MHz

## Embedded Multiplier Specifications

Table 1-26 lists the embedded multiplier specifications for Cyclone IV devices.

**Table 1-26. Embedded Multiplier Specifications for Cyclone IV Devices**

Mode	Resources Used	Performance					Unit
	Number of Multipliers	C6	C7, I7, A7	C8	C8L, I8L	C9L	
9 × 9-bit multiplier	1	340	300	260	240	175	MHz
18 × 18-bit multiplier	1	287	250	200	185	135	MHz

## Memory Block Specifications

Table 1-27 lists the M9K memory block specifications for Cyclone IV devices.

**Table 1-27. Memory Block Performance Specifications for Cyclone IV Devices**

Memory	Mode	Resources Used		Performance					Unit
		LEs	M9K Memory	C6	C7, I7, A7	C8	C8L, I8L	C9L	
M9K Block	FIFO 256 × 36	47	1	315	274	238	200	157	MHz
	Single-port 256 × 36	0	1	315	274	238	200	157	MHz
	Simple dual-port 256 × 36 CLK	0	1	315	274	238	200	157	MHz
	True dual port 512 × 18 single CLK	0	1	315	274	238	200	157	MHz

## Configuration and JTAG Specifications

Table 1-28 lists the configuration mode specifications for Cyclone IV devices.

**Table 1-28. Passive Configuration Mode Specifications for Cyclone IV Devices <sup>(1)</sup>**

Programming Mode	V <sub>CCINT</sub> Voltage Level (V)	DCLK f <sub>MAX</sub>	Unit
Passive Serial (PS)	1.0 <sup>(3)</sup>	66	MHz
	1.2	133	MHz
Fast Passive Parallel (FPP) <sup>(2)</sup>	1.0 <sup>(3)</sup>	66	MHz
	1.2 <sup>(4)</sup>	100	MHz

**Notes to Table 1-28:**

- (1) For more information about PS and FPP configuration timing parameters, refer to the *Configuration and Remote System Upgrades in Cyclone IV Devices* chapter.
- (2) FPP configuration mode supports all Cyclone IV E devices (except for E144 package devices) and EP4CGX50, EP4CGX75, EP4CGX110, and EP4CGX150 only.
- (3) V<sub>CCINT</sub> = 1.0 V is only supported for Cyclone IV E 1.0 V core voltage devices.
- (4) Cyclone IV E devices support 1.2 V V<sub>CCINT</sub>. Cyclone IV E 1.2 V core voltage devices support 133 MHz DCLK f<sub>MAX</sub> for EP4CE6, EP4CE10, EP4CE15, EP4CE22, EP4CE30, and EP4CE40 only.

For more information about the supported maximum clock rate, device and pin planning, IP implementation, and device termination, refer to *Section III: System Performance Specifications* of the *External Memory Interface Handbook*.

Table 1–37 lists the memory output clock jitter specifications for Cyclone IV devices.

**Table 1–37. Memory Output Clock Jitter Specifications for Cyclone IV Devices <sup>(1), (2)</sup>**

Parameter	Symbol	Min	Max	Unit
Clock period jitter	$t_{JIT(per)}$	-125	125	ps
Cycle-to-cycle period jitter	$t_{JIT(cc)}$	-200	200	ps
Duty cycle jitter	$t_{JIT(duty)}$	-150	150	ps

**Notes to Table 1–37:**

- (1) Memory output clock jitter measurements are for 200 consecutive clock cycles, as specified in the JEDEC DDR2 standard.
- (2) The clock jitter specification applies to memory output clock pins generated using DDIO circuits clocked by a PLL output routed on a global clock (GCLK) network.

### Duty Cycle Distortion Specifications

Table 1–38 lists the worst case duty cycle distortion for Cyclone IV devices.

**Table 1–38. Duty Cycle Distortion on Cyclone IV Devices I/O Pins <sup>(1), (2), (3)</sup>**

Symbol	C6		C7, I7		C8, I8L, A7		C9L		Unit
	Min	Max	Min	Max	Min	Max	Min	Max	
Output Duty Cycle	45	55	45	55	45	55	45	55	%

**Notes to Table 1–38:**

- (1) The duty cycle distortion specification applies to clock outputs from the PLLs, global clock tree, and IOE driving the dedicated and general purpose I/O pins.
- (2) Cyclone IV devices meet the specified duty cycle distortion at the maximum output toggle rate for each combination of I/O standard and current strength.
- (3) Cyclone IV E 1.0 V core voltage devices only support C8L, C9L, and I8L speed grades. Cyclone IV E 1.2 V core voltage devices only support C6, C7, C8, I7, and A7 speed grades. Cyclone IV GX devices only support C6, C7, C8, and I7 speed grades.

### OCT Calibration Timing Specification

Table 1–39 lists the duration of calibration for series OCT with calibration at device power-up for Cyclone IV devices.

**Table 1–39. Timing Specification for Series OCT with Calibration at Device Power-Up for Cyclone IV Devices <sup>(1)</sup>**

Symbol	Description	Maximum	Units
$t_{OCTCAL}$	Duration of series OCT with calibration at device power-up	20	$\mu$ s

**Note to Table 1–39:**

- (1) OCT calibration takes place after device configuration and before entering user mode.



Table 1–44 and Table 1–45 list the IOE programmable delay for Cyclone IV GX devices.

**Table 1–44. IOE Programmable Delay on Column Pins for Cyclone IV GX Devices <sup>(1), (2)</sup>**

Parameter	Paths Affected	Number of Settings	Min Offset	Max Offset						Unit
				Fast Corner		Slow Corner				
				C6	I7	C6	C7	C8	I7	
Input delay from pin to internal cells	Pad to I/O dataout to core	7	0	1.313	1.209	2.184	2.336	2.451	2.387	ns
Input delay from pin to input register	Pad to I/O input register	8	0	1.312	1.208	2.200	2.399	2.554	2.446	ns
Delay from output register to output pin	I/O output register to pad	2	0	0.438	0.404	0.751	0.825	0.886	0.839	ns
Input delay from dual-purpose clock pin to fan-out destinations	Pad to global clock network	12	0	0.713	0.682	1.228	1.41	1.566	1.424	ns

**Notes to Table 1–44:**

- (1) The incremental values for the settings are generally linear. For exact values of each setting, use the latest version of the Quartus II software.
- (2) The minimum and maximum offset timing numbers are in reference to setting **0** as available in the Quartus II software.

**Table 1–45. IOE Programmable Delay on Row Pins for Cyclone IV GX Devices <sup>(1), (2)</sup>**

Parameter	Paths Affected	Number of Settings	Min Offset	Max Offset						Unit
				Fast Corner		Slow Corner				
				C6	I7	C6	C7	C8	I7	
Input delay from pin to internal cells	Pad to I/O dataout to core	7	0	1.314	1.210	2.209	2.398	2.526	2.443	ns
Input delay from pin to input register	Pad to I/O input register	8	0	1.313	1.208	2.205	2.406	2.563	2.450	ns
Delay from output register to output pin	I/O output register to pad	2	0	0.461	0.421	0.789	0.869	0.933	0.884	ns
Input delay from dual-purpose clock pin to fan-out destinations	Pad to global clock network	12	0	0.712	0.682	1.225	1.407	1.562	1.421	ns

**Notes to Table 1–45:**

- (1) The incremental values for the settings are generally linear. For exact values of each setting, use the latest version of Quartus II software.
- (2) The minimum and maximum offset timing numbers are in reference to setting **0** as available in the Quartus II software

Table 1-46. Glossary (Part 2 of 5)

Letter	Term	Definitions
J	JTAG Waveform	
K	—	—
L	—	—
M	—	—
N	—	—
O	—	—
P	PLL Block	<p>The following highlights the PLL specification parameters:</p> <div style="border: 1px solid black; padding: 5px; margin-top: 10px;"> <p>Key</p> <p><span style="display: inline-block; width: 10px; height: 10px; background-color: #cccccc; border: 1px solid black;"></span> Reconfigurable in User Mode</p> </div>
Q	—	—

Table 1-46. Glossary (Part 3 of 5)

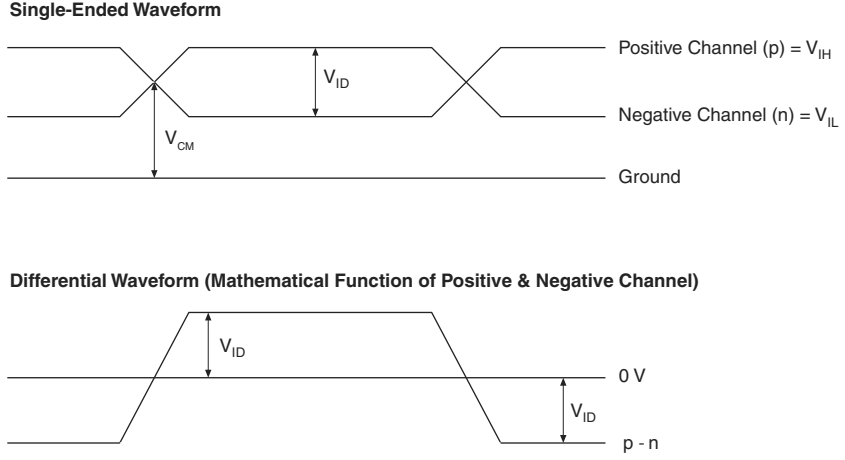
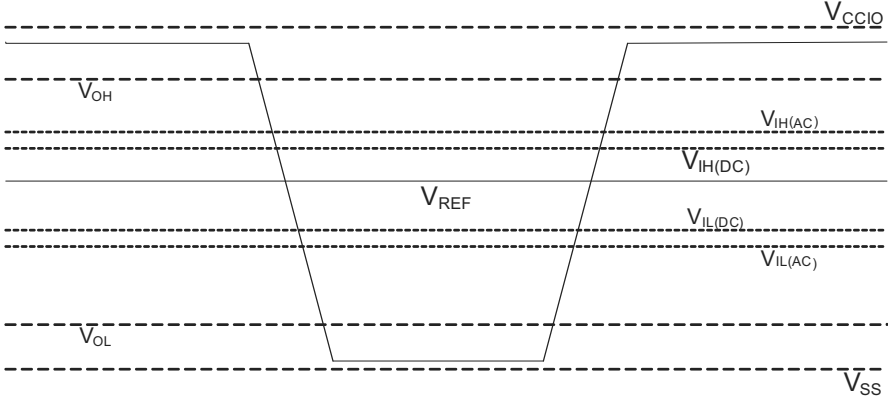
Letter	Term	Definitions
R	$R_L$	Receiver differential input discrete resistor (external to Cyclone IV devices).
	Receiver Input Waveform	<p>Receiver input waveform for LVDS and LVPECL differential standards:</p>  <p><b>Single-Ended Waveform</b></p> <p>Positive Channel (p) = <math>V_{IH}</math></p> <p>Negative Channel (n) = <math>V_{IL}</math></p> <p>Ground</p> <p><b>Differential Waveform (Mathematical Function of Positive &amp; Negative Channel)</b></p> <p>0 V</p> <p>p - n</p>
	Receiver input skew margin (RSKM)	High-speed I/O block: The total margin left after accounting for the sampling window and TCCS. $RSKM = (TUI - SW - TCCS) / 2$ .
S	Single-ended voltage-referenced I/O Standard	 <p>The JEDEC standard for SSTI and HSTL I/O standards defines both the AC and DC input signal values. The AC values indicate the voltage levels at which the receiver must meet its timing specifications. The DC values indicate the voltage levels at which the final logic state of the receiver is unambiguously defined. After the receiver input crosses the AC value, the receiver changes to the new logic state. The new logic state is then maintained as long as the input stays beyond the DC threshold. This approach is intended to provide predictable receiver timing in the presence of input waveform <i>ringing</i>.</p>
	SW (Sampling Window)	High-speed I/O block: The period of time during which the data must be valid to capture it correctly. The setup and hold times determine the ideal strobe position in the sampling window.

Table 1-46. Glossary (Part 4 of 5)

Letter	Term	Definitions
T	$t_C$	High-speed receiver and transmitter input and output clock period.
	Channel-to-channel-skew (TCCS)	High-speed I/O block: The timing difference between the fastest and slowest output edges, including $t_{CO}$ variation and clock skew. The clock is included in the TCCS measurement.
	$t_{cin}$	Delay from the clock pad to the I/O input register.
	$t_{CO}$	Delay from the clock pad to the I/O output.
	$t_{cout}$	Delay from the clock pad to the I/O output register.
	$t_{DUTY}$	High-speed I/O block: Duty cycle on high-speed transmitter output clock.
	$t_{FALL}$	Signal high-to-low transition time (80–20%).
	$t_H$	Input register hold time.
	Timing Unit Interval (TUI)	High-speed I/O block: The timing budget allowed for skew, propagation delays, and data sampling window. (TUI = $1/(\text{Receiver Input Clock Frequency Multiplication Factor}) = t_C/w$ ).
	$t_{INJITTER}$	Period jitter on the PLL clock input.
	$t_{OUTJITTER\_DEDCLK}$	Period jitter on the dedicated clock output driven by a PLL.
	$t_{OUTJITTER\_IO}$	Period jitter on the general purpose I/O driven by a PLL.
	$t_{pllcin}$	Delay from the PLL inclk pad to the I/O input register.
	$t_{pllcout}$	Delay from the PLL inclk pad to the I/O output register.
Transmitter Output Waveform	<p>Transmitter output waveforms for the LVDS, mini-LVDS, PPDS and RSDS Differential I/O Standards:</p> <p><b>Single-Ended Waveform</b></p> <p>Positive Channel (p) = <math>V_{OH}</math>  Negative Channel (n) = <math>V_{OL}</math>  Ground</p> <p><b>Differential Waveform (Mathematical Function of Positive &amp; Negative Channel)</b></p> <p>0 V  p - n</p>	
$t_{RISE}$	Signal low-to-high transition time (20–80%).	
$t_{SU}$	Input register setup time.	
U	—	—

## Document Revision History

Table 1-47 lists the revision history for this chapter.

**Table 1-47. Document Revision History**

Date	Version	Changes
March 2016	2.0	Updated note (5) in Table 1-21 to remove support for the N148 package.
October 2014	1.9	Updated maximum value for $V_{CCD\_PLL}$ in Table 1-1. Removed extended temperature note in Table 1-3.
December 2013	1.8	Updated Table 1-21 by adding Note (15).
May 2013	1.7	Updated Table 1-15 by adding Note (4).
October 2012	1.6	<ul style="list-style-type: none"> <li>■ Updated the maximum value for <math>V_I</math>, <math>V_{CCD\_PLL}</math>, <math>V_{CCIO}</math>, <math>V_{CC\_CLKIN}</math>, <math>V_{CCH\_GXB}</math>, and <math>V_{CCA\_GXB}</math> in Table 1-1.</li> <li>■ Updated Table 1-11 and Table 1-22.</li> <li>■ Updated Table 1-21 to include peak-to-peak differential input voltage for the Cyclone IV GX transceiver input reference clock.</li> <li>■ Updated Table 1-29 to include the typical <math>D_{CLK}</math> value.</li> <li>■ Updated the minimum <math>f_{HSCLK}</math> value in Table 1-31, Table 1-32, Table 1-33, Table 1-34, and Table 1-35.</li> </ul>
November 2011	1.5	<ul style="list-style-type: none"> <li>■ Updated “Maximum Allowed Overshoot or Undershoot Voltage”, “Operating Conditions”, and “PLL Specifications” sections.</li> <li>■ Updated Table 1-2, Table 1-3, Table 1-4, Table 1-5, Table 1-8, Table 1-9, Table 1-15, Table 1-18, Table 1-19, and Table 1-21.</li> <li>■ Updated Figure 1-1.</li> </ul>
December 2010	1.4	<ul style="list-style-type: none"> <li>■ Updated for the Quartus II software version 10.1 release.</li> <li>■ Updated Table 1-21 and Table 1-25.</li> <li>■ Minor text edits.</li> </ul>
July 2010	1.3	<p>Updated for the Quartus II software version 10.0 release:</p> <ul style="list-style-type: none"> <li>■ Updated Table 1-3, Table 1-4, Table 1-21, Table 1-25, Table 1-28, Table 1-30, Table 1-40, Table 1-41, Table 1-42, Table 1-43, Table 1-44, and Table 1-45.</li> <li>■ Updated Figure 1-2 and Figure 1-3.</li> <li>■ Removed SW Requirement and TCCS for Cyclone IV Devices tables.</li> <li>■ Minor text edits.</li> </ul>
March 2010	1.2	<p>Updated to include automotive devices:</p> <ul style="list-style-type: none"> <li>■ Updated the “Operating Conditions” and “PLL Specifications” sections.</li> <li>■ Updated Table 1-1, Table 1-8, Table 1-9, Table 1-21, Table 1-26, Table 1-27, Table 1-31, Table 1-32, Table 1-33, Table 1-34, Table 1-35, Table 1-36, Table 1-37, Table 1-38, Table 1-40, Table 1-42, and Table 1-43.</li> <li>■ Added Table 1-5 to include ESD for Cyclone IV devices GPIOs and HSSI I/Os.</li> <li>■ Added Table 1-44 and Table 1-45 to include IOE programmable delay for Cyclone IV E 1.2 V core voltage devices.</li> <li>■ Minor text edits.</li> </ul>